	Ty pe	Hits	Search Text	DBs	Time Stamp	Com ments	Error Defini tion	Error s
1	BR S	708 48	34/\$.ccls. 134/\$.ccls.	USPAT; EPO; JPO	2004/03 /01			0
2	BR S	344	(34/\$.ccls. 134/\$.ccls.) and (substrate wafer) and vacuum and cassette	USPAT; EPO; JPO	2004/03 /01 11:45			0
3	BR S	2	((34/\$.ccls.) and (substrate wafer) and vacuum and cassette) and (transfer with cassette) and (original with cassette with return)	USPAT; EPO; JPO	2004/03 /01 11:46			0
4	BR S	50	((34/\$.ccls. 134/\$.ccls.) and (substrate wafer) and vacuum and cassette) and (transfer with cassette) and (original with cassette)	USPAT; EPO; JPO	2004/03 /01 11:49			0
5	BR S	43	((34/\$.ccls. 134/\$.ccls.) and (substrate wafer) and vacuum and cassette) and (transfer with cassette) and (original with cassette) and dummy	USPAT; EPO; JPO	2004/03 /02 09:14			0
6	BR S	1	"4923584".PN.	USPAT	2004/03 /01			0
7	BR S	1	4923584.pn. and (plasma dummy)	USPAT; EPO; JPO	2004/03 /01			0

	Ty pe	Hits	Search Text	DBs	Time Stamp	Com ments	Error Defini tion	Error s
8	BR S	1	(((34/\$.ccls.) and (substrate wafer) and vacuum and cassette) and (transfer with cassette) and (original with cassette) and dummy) not kato	USPAT; EPO; JPO	2004/03 /02 09:15			0
9	BR S	43	((34/\$.ccls. 134/\$.ccls.) and (substrate wafer) and vacuum and cassette) and (transfer with cassette) and (original with cassette) and dummy	USPAT; EPO; JPO	2004/03 /02 09:16			0

	Ty pe	Hits	Search Text	DBs	Time Stamp	Com ments	Error Defini tion	Error s
10	BRS	48	("3652444" "3981791" "4138306" "4226897" "4311427" "4313783" "4318767" "4449885" "4457661" "4563240" "4576698" "4634331" "4643629" "4705951" "4705951" "4715764" "4824309" "4836733" "4836733" "4836905" "4895107" "4902934" "4903937" "4903937" "4903937" "4915564" "4917556" "4917556" "4917556" "4923584" "4924890" "4936329" "4951601"	USPAT	2004/03 /02 09:15			0

	Ty pe	Hits	Search Text	DBs	Time Stamp	Com ments	Error Defini tion	Error s
11	BRS	1	(("3652444" "3981791" "4138306" "4226897" "4311427" "4313783" "4313815" "4449885" "4457661" "4534314" "4563240" "4576698" "4634331" "4643629" "4715764" "4824309" "4836733" "4836905" "4851101" "4895107" "4902934" "4902934" "4903937" "4909695" "4911597" "4915564" "4917556" "4923584" "4924890" "4936329" "4951601"	USPAT; EPO; JPO	2004/03 /02 09:16			0
12	BR S	10	(34/\$.ccls. 134/\$.ccls.) and ((substrate wafer) with dummy) and @py<1990	USPAT; EPO; JPO	2004/03 /02 09:28			0

•	Ty pe	Hits	Search Text	DBs	Time Stamp	Com ments	Error Defini tion	Error s
13	BR S	13	(34/\$.ccls. 134/\$.ccls.) and ((substrate wafer) with dummy) and @py<1993	USPAT; EPO; JPO	2004/03 /02 09:28			0
1 /1 1	BR S	3	((34/\$.ccls. 134/\$.ccls.) and ((substrate wafer) with dummy) and @py<1993) not ((34/\$.ccls. 134/\$.ccls.) and ((substrate wafer) with dummy) and @py<1990)	USPAT; EPO; JPO	2004/03 /02 09:30			0
15	BR S	63	kato and (wafer substrate) and 34/\$.ccls.	USPAT; EPO; JPO	2004/03 /02 09:30			0
16	BR S	14	(kato and (wafer substrate) and 34/\$.ccls.) and kathryn	USPAT; EPO; JPO	2004/03 /02 09:31			0

Ty pe	Hits	Search Text	DBs	Time Stamp	Com ments	Error Defini tion	Error s
17 BR	49	("3652444" "3981791" "4138306" "4226897" "4311427" "4313815" "4318767" "4449885" "4457661" "4534314" "4563240" "4576698" "4634331" "4643629" "4715764" "4824309" "4836733" "4836905" "4851101" "4895107" "4902934" "4902934" "4903937" "4903937" "4903937" "4903937" "4915564" "4917556" "4917556" "4923584" "4924890" "4936329" "4951601"	USPAT	2004/03 /02 09:31			0

Ty pe H	lits	Search Text	DBs	Time Stamp	Com ments	Error Defini tion	Error s
8 S 3		(("3652444" "3981791" "4138306" "4226897" "4311427" "4313783" "4318767" "4449885" "4457661" "4534314" "4576698" "4576698" "4634331" "4643629" "4715764" "4824309" "4836733" "4836905" "4851101" "4895107" "4902934" "4902934" "4903937" "4909695" "4911597" "4915564" "4923584" "4924890" "4936329" "4951601"	USPAT;	2004/03 /02 09:31			0

	Document ID	Issue Date		1	Curren t XRef	Inventor
1	US 5169407 A	1992 1208	Method of determining end of cleaning of semiconductor manufacturing apparatus	29/25. 01	134/1; 204/19 2.33; 204/29 8.32; 216/59	Mase, Yasukazu et al.
2	US 5016663 A	1991 0521	Method of determining end of cleaning of semiconductor manufacturing apparatus	134/1	134/1.1 ; 204/19 2.33; 204/29 8.32;	Mase, Yasukazu et al.
3	US 4827867 A	1989 0509	Resist developing apparatus	118/6 4	118/32 0; 118/32 6; 118/52; 118/66 7; 134/10 5; 134/20 0; 134/90 2; 165/15 6; 165/16 9; 165/28 9; 165/64; 427/42 2	Takei, Toshitaka et al.

	Document ID	Issue Date	l itle	1	Curren t XRef	Inventor
4	US 4597989 A	1986	Method of depositing silicon films with reduced structural defects	427/9 9	134/22. 18; 134/37; 438/68 4:	Wonsowicz, Casimir J. et al.
5	US 4529474 A	1985 0716	Method of cleaning apparatus for forming deposited film	134/1.	118/50. 1; 118/62 0; 118/71 5; 134/1; 204/19 2.32; 204/29 8.33; 216/79; 427/58	Fujiyama, Yasutomo et al.
6	US 4512812 A	0423	Method for reducing phosphorous contamination in a vacuum processing chamber	134/2 1		Liebert, Reuel B. et al.
7		: :	Method for drying semiconductor substrates	34/25 9		Takagi, Mikio et al.

	Document ID	Issue Date	Title	1	Curren t XRef	Inventor
וע ו	US 4201579 A		Method for removing photoresist by hydrogen plasma	23	134/1; 134/1.2; 204/19 2.32; 216/59; 257/E2 1.249; 257/E2 1.256; 315/11 1.21; 430/32 9; 430/49	Robinson, Frederick J.
9	Љ 03064916 А	1991 0320	WAFER WASHING METHOD		134/90 2	MIYAMOT O, YASUNOR I
10	JP 63185032 A	0730	ETCHING APPARATUS FOR SILICON SUBSTRATE		134/41	NONAKA, TSUTOMU
11	JР 62023116 A	:	WET SEMICONDUCTOR MANUFACTURING EQUIPMENT		34/58	EJIRI, IWAO
17)	JР 59229822 A	1984 1224	ETCHING APPARATUS		134/1; 257/E2 1.215	NITTA, TAKEHISA
13	Љ 58009325 A	:	SELF-ROTATIONAL WAFER DRYER		34/58; 34/108	OKUMUR A, KATSUYA